60V LOW $V_{CE(sat)}$ NPN SURFACE MOUNT TRANSISTOR

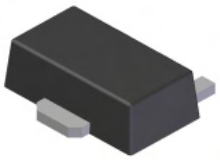
Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DXT751)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free "Green" Device (Note 2)**

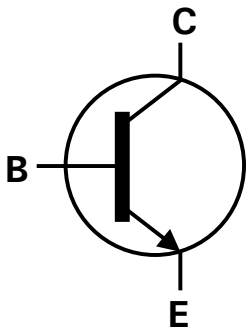
Mechanical Data

- Case: SOT89
- Case material: molded Plastic. “Green” molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)

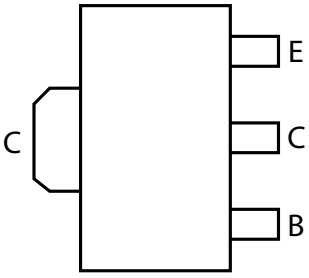
SOT89



Top View



Device symbol



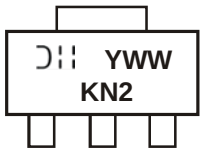
Top View
Pinout

Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXT651-13	KN2	13	12	2,500

Notes: 1. No purposefully added lead.
2. “Green” devices, Halogen and Antimony Free, Diodes Inc’s “Green” Policy can be found on our website at http://www.diodes.com
3. For Packaging Details, go to our website at http://www.diodes.com.

Marking Information



KN2 = Product Type Marking Code
= Manufacturer’s Marking Code
YWW = Date Code Marking
Y = Last digit of year (ex: 7 = 2007)
WW = Week code (01 – 53)

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Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	3	A
Peak Pulse Collector Current	I_{CM}	6	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P_D	1	W
Thermal Resistance, Junction to Ambient Air (Note 4)	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	18.2	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
OFF CHARACTERISTICS (Note 5)						
Collector-Base Breakdown Voltage	BV_{CBO}	80	—	—	V	I_C = 100μA, I_E = 0
Collector-Emitter Breakdown Voltage	BV_{CEO}	60	—	—	V	I_C = 10mA, I_B = 0
Emitter-Base Breakdown Voltage	BV_{EBO}	5	—	—	V	I_E = 100μA, I_C = 0
Collector-Base Cutoff Current	I_{CBO}	—	—	0.1 10	μA	V_{CB} = 60V, I_E = 0 V_{CB} = 60V, I_E = 0, T_A = 100°C
Emitter-Base Cutoff Current	I_{EBO}	—	—	0.1	μA	V_{EB} = 4V, I_C = 0
ON CHARACTERISTICS (Note 5)						
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	0.08 0.23	0.3 0.6	V V	I_C = 1A, I_B = 100mA I_C = 3A, I_B = 300mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	0.85	1.25	V	I_C = 1A, I_B = 100mA
Base-Emitter Turn-On Voltage	$V_{BE(on)}$	—	0.8	1	V	V_{CE} = 2V, I_C = 1A
DC Current Gain	h_{FE}	70 100 80 40	200 200 185 120	— 300 — —	—	V_{CE} = 2V, I_C = 50mA V_{CE} = 2V, I_C = 500mA V_{CE} = 2V, I_C = 1A V_{CE} = 2V, I_C = 2A
AC CHARACTERISTICS						
Transition Frequency	f_T	140	200	—	MHz	V_{CE} = 5V, I_C = 100mA, f = 100MHz
Output Capacitance	C_{obo}	—	—	30	pF	V_{CB} = 10V, f = 1MHz
Switching Times	t_{on} t_{off}	— —	35 230	— —	ns ns	V_{CC} = 10V. I_C = 500mA, I_{B1} = I_{B2} = 50mA

Notes: 4. Device mounted on FR-4 PCB
5. Measured under pulsed conditions. Pulse width = 300 s. Duty cycle ≤2%.

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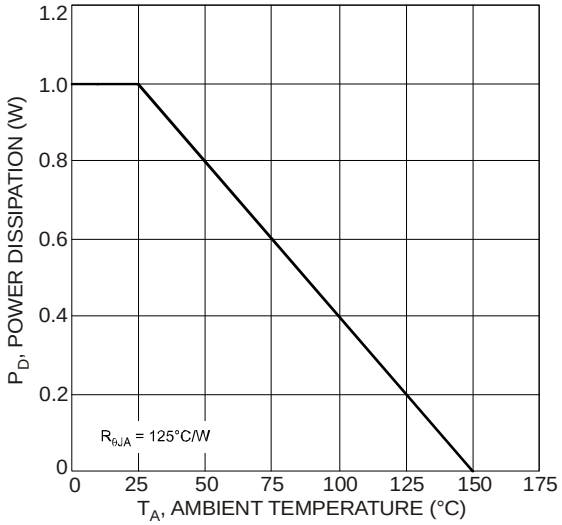

Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

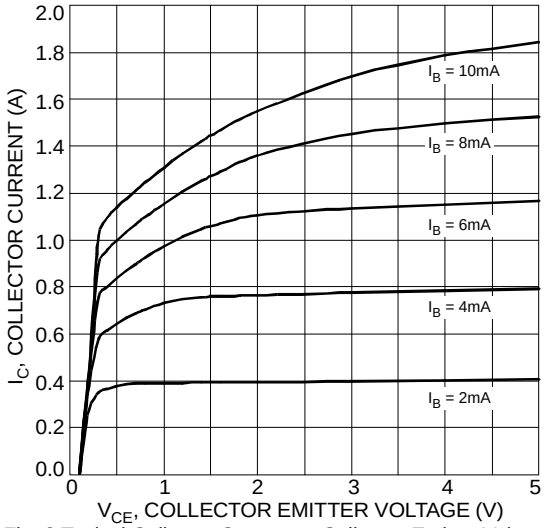

Fig. 2 Typical Collector Current vs.Collector-Emitter Voltage

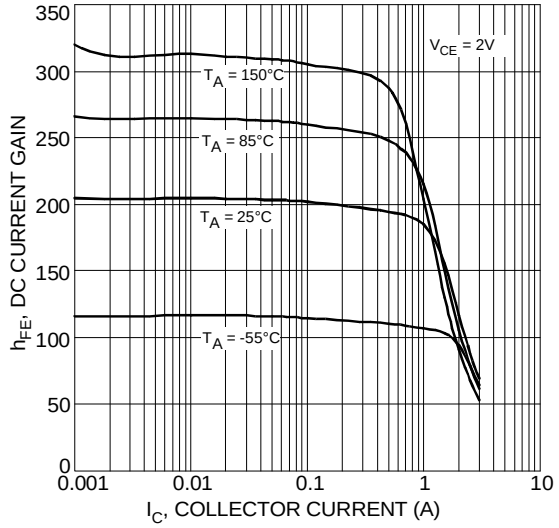

Fig. 3 Typical DC Current Gain vs. Collector Current

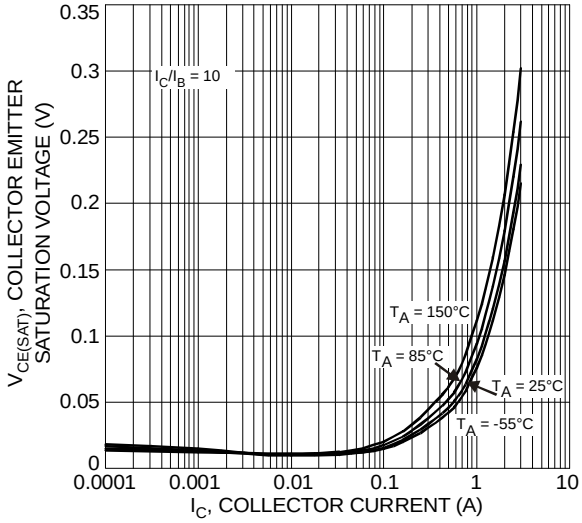

Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

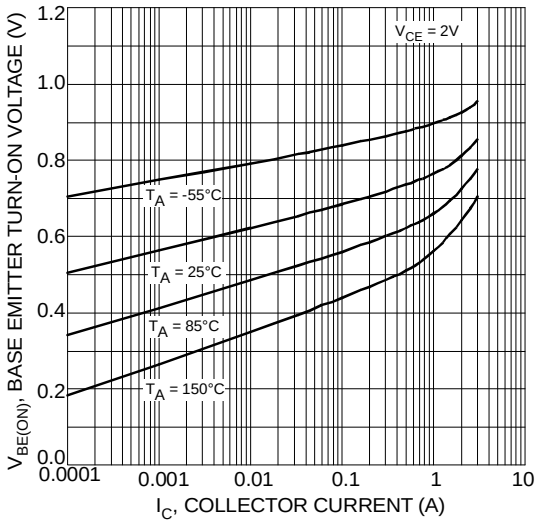

Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

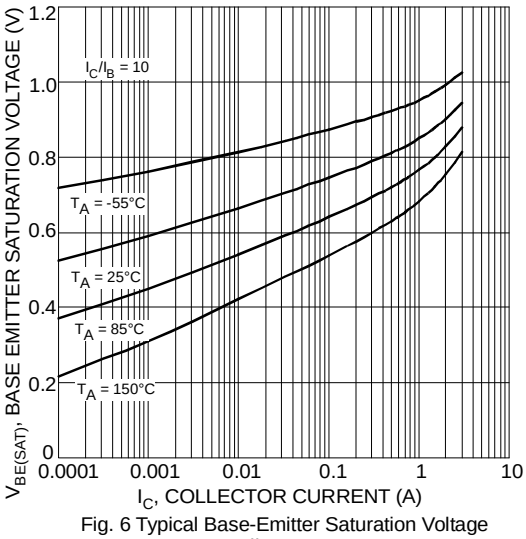

Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

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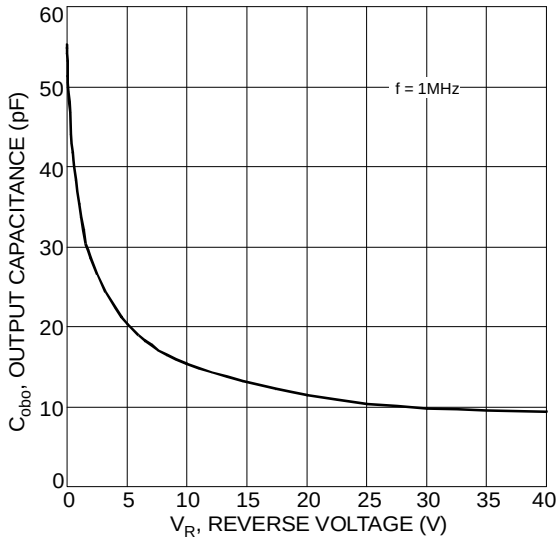


Fig. 7 Typical Output Capacitance Characteristics

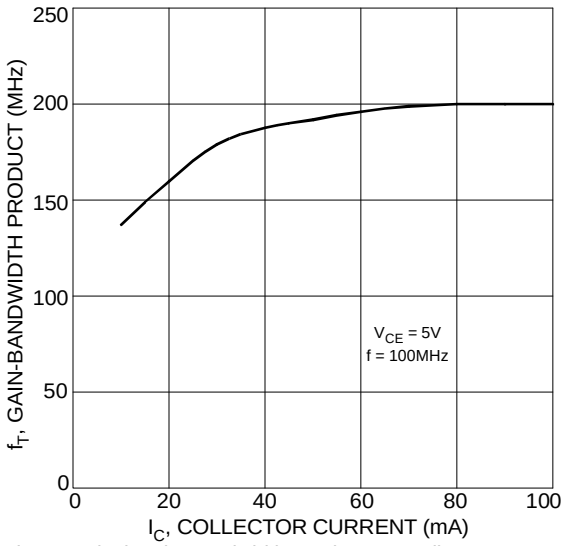
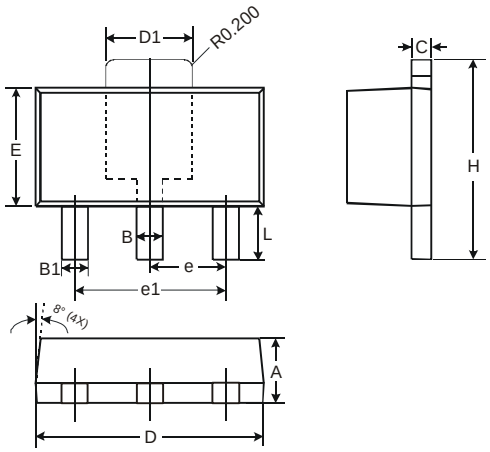


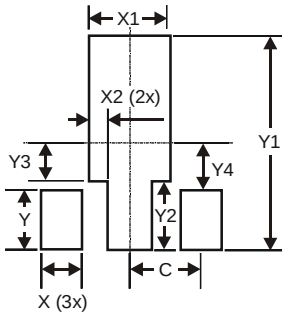
Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions



SOT89		
Dim	**Min**	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.43
D	4.40	4.60
D1	1.52	1.83
E	2.29	2.60
e	1.50 Typ	
e1	3.00 Typ	
H	3.94	4.25
L	0.89	1.20
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500

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- Консультации по применению компонента;
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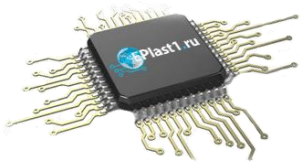
- Защита от снятия компонента с производства.



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